

Scilab Textbook Companion for  
Solid State Physics  
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# Book Description

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Scilab numbering policy used in this document and the relation to the above book.

**Exa** Example (Solved example)

**Eqn** Equation (Particular equation of the above book)

**AP** Appendix to Example(Scilab Code that is an Appednix to a particular Example of the above book)

For example, Exa 3.51 means solved example 3.51 of this book. Sec 2.3 means a scilab code whose theory is explained in Section 2.3 of the book.

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# Chapter 1

## Bonding in Solids

Scilab code Exa 1.1 Stability of gaseous molecules

```
1 // Scilab Code Ex1.1 : Page-1.8 (2004)
2 clc; clear;
3 N = 6.022e+23; // Avogadro Number; /mol
4 E_A = 502; // First ionization energy of A
   atom, kJ/mol
5 E_B = -335; // Electron affinity for B atom,
   kJ
6 r = 3e-10; // Velocity of the particle at the
   mean position, angstrom
7 E_o = 8.85e-12; // Permittivity of free space, C/N^2-
   m^2
8 e = 1.6e-19; // Electronic charge, C
9 E_C = N*(-e^2)/(4*pi*E_o*r)*1e-03; // The
   coulombic electrostatic attraction energy, kJ/mol
10 E = E_A + E_B + E_C; // Net change in energy per
   mol, kJ/mol
11 printf("\\nNet change in energy per mol = %3d kJ/mol"
   , E);
12 disp("Since net change in energy is negative, the
   molecule A+B- is stable.");
13
```



```

14 // Result
15 // Net change in energy per mol = -295 kJ/mol
16 // Since net change in energy is negative, the
    molecule A+B- is stable.

```

---

### Scilab code Exa 1.2 Energy and separation in KCl ion pair

```

1 // Scilab Code Ex1.2 : Page-1.8 (2004)
2 clc;clear;
3 A = 4.1; // Ionization energy of K, eV
4 B = 3.6; // Electron affinity of Cl, eV
5 C = A - B; // Net energy to produce the ion pair,
    eV
6 E = C; // Coulomb energy, eV
7 e = 1.6e-19; // Electronic charge, C
8 E_o = 8.85e-12; // Permittivity of free space, C/N^2-
    m^2
9 R = e/(4*pi*E_o*C); // R is the separation
    between K and Cl, nm
10 printf("\nThe coulomb energy E = %3.1f eV", E);
11 printf("\nSeparation between K and Cl, R = %4.2f nm"
    , R/1e-09);
12
13 // Result
14 // The coulomb energy E = 0.5 eV
15 // Separation between K and Cl, R = 2.88 nm

```

---

### Scilab code Exa 1.3 Bond energy of NaCl molecule

```

1 // Scilab Code Ex1.3 : Bond energy of NaCl molecule
    Page-1.9 (2004)
2 clc;clear;
3 A = 5.14; // Ionization energy of Na, eV

```

```

4 B = 3.65; // Electron affinity of Cl, eV
5 r0 = 236e-12; // Inter ionic equilibrium distance,
    m
6 e = 1.6e-19; // Electronic charge, C
7 E_o = 8.85e-12; // Permittivity of free space, C/N^2-
    m^2
8 Ue = -e/(4*pi*E_o*r0); // Potential energy to
    produce the ion pair, eV
9 BE = -Ue-A+B
10 printf("\nThe potential energy Ue = %2.1f eV",Ue);
11 printf("\nThe Binding energy BE = %4.2f eV",BE);
12
13 // Result
14 // The potential energy Ue = -6.1 eV
15 // The Binding energy BE = 4.61 eV

```

---

# Chapter 2

## Crystal Structure

**Scilab code Exa 2.1** Maximum radius of interstitial sphere in BCC

```
1 // Scilab Code Ex2.1 Page-2.21 (2004)
2 clc; clear;
3 r = 1; // For simplicity assume radius of atom to
        be unity, unit
4 a = 4*r/sqrt(3); // Lattice constant, unit
5 R = (a-2*r)/2; // R be the radius of
        interstitial sphere that can fit into void, unit
6
7 printf ("\nRadius of interstitial sphere that can
        fit into void R = %5.3fr", R);
8
9 // Result
10 // Radius of interstitial sphere that can fit into
    void R = 0.155r
```

---

**Scilab code Exa 2.2** Volume Phase change BCC to FCC

```
1 // Scilab Code Ex2.2 : Page-2.22 (2004)
```

```

2  clc;clear;
3  r1 = 1.258e-10; // Radius of atom for BCC, m
4  a = 4*r1/(3^(0.5)); // Lattice constant for BCC
    atom, m
5  V_bcc = a^3; // Volume of unit cell of BCC , in m^3
6  V_one = V_bcc/2; // Volume occupied by one atom in
    BCC, in m^3
7  r2 = 1.292e-10; // Radius of atom for FCC, m
8  b = 2*(sqrt(2))*r2 // Lattice constant for FCC
    atom
9  V_fcc = b^3; // Volume of unit cell of FCC , in m^3
10 V_two = V_bcc/4; // Volume occupied by one atom in
    FCC, in m^3
11 DV = (V_one-V_two)/V_one; // Change in volume ,
    percentage
12
13 printf("\\nChange in volume DV =%3.1f percentage.",
    DV);
14
15 // Result
16 // Change in volume DV =0.5 percentage.

```

---

### Scilab code Exa 2.3 Calculation of volume and density of Zinc

```

1 // Scilab Code Ex2.3 : Page-2.23 (2004)
2 clc;clear;
3 a = 0.27e-9; // Nearest neighbour distance , m
4 c = 0.494e-9; // Height of unit cell , m
5 V = 3*(sqrt(3))*(a^2)*c/2; // Volume of unit cell
    of HCP , in metre cube
6 N = 6.023e+26; // Avodagro number , per k-mol
7 M = 65.37; // Atomic weight of zinc ,
8 rho = 6*M/(V*N); // Density of zinc , kg per
    metre cube
9 printf("\\nVolume = %4.3e metre cube" , V);

```

```

10 printf("\nDensity of zinc = %d kg per metre cube",
        rho);
11
12 // Result
13 // Volume = 9.356e-29 metre cube
14 // Density of zinc = 6960 kg per metre cube

```

---

#### Scilab code Exa 2.4 Maximum radius of interstitial sphere in FCC

```

1 // Scilab Code Ex2.4 : Page-2.23 (2004)
2 clc;clear;
3 r = 1; // For simplicity assume radius of atom to
        be unity, unit
4 a = 4*r/sqrt(2); // Lattice constant, unit
5 R = (a/2)-r; // R be the radius of interstitial
        sphere that can fit into void, unit
6
7 printf ("\nMaximum Radius of interstitial sphere
        that can fit into FCC = %5.3fr", R);
8
9 // Result
10 // Maximum Radius of interstitial sphere that can
        fit into FCC = 0.414r

```

---

#### Scilab code Exa 2.5 Density of diamond

```

1 // Scilab Code Ex2.5 : Page-2.24 (2004)
2 clc;clear;
3 a = 0.356e-9; // Cube edge of diamond, m
4 n = 8/a^3; // Number of atoms per unit volume,
        per metre cube
5 M = 12.01; // Atomic weight of Carbon, g per mol
6 N = 6.023e+26; // Avagadro number, per kmol

```

```

7 m = M/N;      // Mass of one carbon atom, kg
8 rho = m*n;    // Density of diamond, kg per metre
                cube
9 printf("\nDensity of diamond = %4.0f kg per metre
                cube", round(rho));
10
11 // Result
12 // Density of diamond = 3536 kg per metre cube

```

---

**Scilab code Exa 2.6** Distance between two adjacent atoms in NaCl

```

1 // Scilab Code Ex2.6 : Page-2.25 (2004)
2 clc;clear;
3 M = 58.5; // Molecular weight of Carbon, g per mol
4 N = 6.023e+23; // Avagadro number, per mol
5 m = M/N; // Mass of one NaCl molecule, g
6 n = 2.18/m; // Number of NaCl molecules per unit
                volume, molecules per cm cube
7 n1 = 2*n; // Since NaCl is a diatomic, number of
                atoms per unit volume is twice
8 a = 1/n1^(1/3); // Distance between two adjacent
                atoms in NaCl, angstrom
9
10 printf("\nDistance between two adjacent atoms in
                NaCl = %4.2f angstrom", a/1e-8);
11
12 // Result
13 // Distance between two adjacent atoms in NaCl =
                2.81 angstrom

```

---

**Scilab code Exa 2.7** Density of copper crystal

```

1 // Scilab Code Ex2.7: Page-2.25 (2004)

```

```
2 clc;clear;
3 M = 63.5; // Atomic weight of Copper, g per mol
4 N = 6.023e+23; // Avagadro number, per mol
5 r = 1.278e-8; // Atomic radius of copper, cm
6 m = M/N; // Mass of one Cu atom, kg
7 a = (4*r)/sqrt(2); // Distance between two adjacent
    atom in Cu, angstrom
8 n1 = 4*m; // Since number of atom per unit cell is
    4
9 d = n1/a^3; // Density of copper, kg per metre
    cube
10
11 printf("\\nDensity of copper = %4.2f g per cm cube",
    d);
12
13 // Result
14 // Density of copper = 8.93 g per cm cube
```

---

# Chapter 3

## Crystal Planes and Defects

Scilab code Exa 3.1 Number of atoms per square mm in SC

```
1 // Scilab Code Ex3.1 : Page-3.4 (2004)
2 // In a SC structure number of planes are having
   three arrangement (100),(110) and (111)
3 clc;clear;
4 a = 1; // For simplicity lattice constant is
   taken to be unity
5 A_100 = a^2; // Area of the plane (100), mm^2
6 N_100 = 1/A_100; // Number of atoms along (100)
   plane, atoms per square mm
7 A_110 = sqrt(2)*a^2; // Area of the plane (110),
   mm^2
8 N_110 = 1/A_110; // // Number of atoms along
   (110) plane, atoms per square mm
9 A_111 = 1/2*a*sqrt(2)*sqrt(2)*a^2*cosd(30); //
   Area of the plane (110), mm^2
10 A_111t = 0.5; // Total no of atoms in (111)
   plane
11 N_111 = A_111t/A_111; // // Number of atoms
   along (110) plane, atoms per square mm
12 printf("\\nNumber of atoms along (100) plane= %d /a^2
   atoms per square mm", N_100);
```



```

13 printf("\nNumber of atoms along (110) plane= %f
    atoms per square mm", N_110);
14 printf("\nNumber of atoms along (111) plane= %5.3 f /
    a^2 atoms per square mm", N_111);
15 // Result
16 // Number of atoms along (100) plane= 1 /a^2 atoms
    per square mm
17 // Number of atoms along (110) plane= 0.707107
    atoms per square mm
18 // Number of atoms along (111) plane= 0.577 /a^2
    atoms per square mm

```

---

**Scilab code Exa 3.2** Maximum radius of sphere in BCC lattice

```

1 // Scilab Code Ex3.2 : Page-3.5(2004)
2 clc;clear;
3 r = 1; // For simplicity assume radius of atom to
    be unity, unit
4 a = 4*r/sqrt(3); // Lattice constant, unit
5 R = (a/2)-r; // R be the radius of interstitial
    sphere that can fit into void, unit
6 printf ("\nMaximum Radius of sphere that can fit
    into BCC = %5.3 fr", R);
7
8 // Result
9 // Maximum Radius of sphere that can fit into BCC =
    0.155r

```

---

**Scilab code Exa 3.3** Volume change during BCC to FCC

```

1 // Scilab Code Ex3.3 : Page-3.6 (2010)
2 clc;clear;
3 r1 = 1.258e-10; // Atomic radius in BCC, metre

```

```

4 a1 = 4*r1/sqrt(3); // Lattice constant for BCC,
  metre
5 V1 = a1^3; // Volume of unit cell in BCC, metre
  cube
6 Vpa = V1/2; // Volume occupied by one atom in BCC,
  metre cube
7 r2 = 1.292e-10; // Atomic radius in FCC, metre
8 a2 = 2*r2*sqrt(2); // Lattice constant for FCC,
  cube
9 V2 = a2^3; // Volume of unit cell in FCC, meter
  cube
10 Vpa1 = V2/4; // Volume occupied by one atom in FCC,
  metre cube
11 dV = (Vpa-Vpa1)/Vpa*100; // Change in volume,
  percentage
12 printf("\nChange in volume in percentage = %4.3f
  percentage", dV);
13
14 // Result
15 // Change in volume in percentage = 0.493 percentage

```

---

#### Scilab code Exa 3.4 Volume and density of unit cell in HCP Zn structure

```

1 // Scilab Code Ex3.4 : Page-3.7 (2010)
2 clc;clear;
3 a = 0.27e-9; // Lattice constant for BCC, metre
4 c = 0.494e-9; // Height of the unit cell, metre
5 M = 65.37; // Atomic weight of zn, kg
6 N = 6.02e+26; // Avogadro number per k mol
7 m = 6*M/N; // Mass per unit cell in HCP structure,
  kg
8 V = 3*sqrt(3)*a^2*c/2; // Volume of unit cell in
  HCP, metre cube
9 rho = m/V; // Density of HCP Zn structure, kg per
  metrecube

```

```

10
11 printf("\nVolume of HCP Zn structure = %4.3e
    metrecube", V);
12 printf("\nDensity of HCP Zn structure = %4.0f kg per
    metrecube", rho);
13
14 // Result
15 // Volume of HCP Zn structure = 9.356e-29 metrecube
16 // Density of HCP Zn structure = 6963 kg per
    metrecube

```

---

**Scilab code Exa 3.5** Interplanar spacing in 110 and 212 planes in FCC lattice

```

1 /// Scilab Code Ex3.5 : Page-3.5 (2004)
2 clc;clear;
3 r = 0.1278; // Atomic radius , nm
4 a = 4*r/sqrt(2); // Lattice constant , nm
5 h1 = 1, k1 = 1, l1 = 0; // Miller Indices of
    (110) planes
6 d_110 = a/sqrt(h1^2 + k1^2 + l1^2); //
    Interplanar spacing for (110) planes , nm
7 h2 = 2, k2 = 1, l2 = 2; // Indices of third set
    of parallel planes
8 d_212 = a/sqrt(h2^2 + k2^2 + l2^2); //
    Interplanar spacing for (111) planes , nm
9 printf("\nInterplanar spacing for (110) planes = %6
    .4f nm", d_110);
10 printf("\nInterplanar spacing for (212) planes = %6
    .4f nm", d_212);
11
12 // Result
13 // Interplanar spacing for (110) planes = 0.2556 nm
14 // Interplanar spacing for (212) planes = 0.1205 nm

```

---

**Scilab code Exa 3.6** Ratio of interplanar spacing in SC lattice

```
1 // Scilab Code Ex3.6 : Page-3.8 (2004)
2 clc;clear;
3 a = 1; // For simplicity we assume a to be unity,
  unit
4 h1 = 1, k1 = 0, l1 = 0; // Indices of first set
  of parallel planes
5 d_100 = a/sqrt(h1^2 + k1^2 + l1^2); //
  Interplanar spacing for (100) planes, unit
6 h2 = 1, k2 = 1, l2 = 0; // Indices of second set
  of parallel planes
7 d_110 = a/sqrt(h2^2 + k2^2 + l2^2); //
  Interplanar spacing for (110) planes, unit
8 h3 = 1, k3 = 1, l3 = 1; // Indices of third set
  of parallel planes
9 d_111 = a/sqrt(h3^2 + k3^2 + l3^2); //
  Interplanar spacing for (111) planes, unit
10 printf("\nd_100 : d_110 : d_111 = %1d : %4.2f : %4.2
  f", d_100, d_110, d_111);
11
12 // Result
13 // d_100 : d_110 : d_111 = 1 : 0.71 : 0.58
```

---

**Scilab code Exa 3.7** Miller indices of a plane in SC lattice

```
1 // Scilab Code Ex3.7 : Page-3.8 (2004)
2 clc;clear;
3 m = 1; n = 1/2; p = 3; // Coefficients of intercepts
  along three axes
4 m_inv = 1/m; // Reciprocate the first
  coefficient
```

```

5 n_inv = 1/n;          // Reciprocate the second
  coefficient
6 p_inv = 1/p;          // Reciprocate the third
  coefficient
7 mul_fact = double(lcm(int32([1, 1, 3]))); // Find l.
  c.m. of 1, 1 and 3
8 m1 = m_inv*mul_fact; // Clear the first fraction
9 m2 = n_inv*mul_fact; // Clear the second fraction
10 m3 = p_inv*mul_fact; // Clear the third fraction
11 printf("\nThe required miller indices are : (%d %d
  %d) ", m1,m2,m3);
12
13 // Result
14 // The required miller indices are : (3 6 1)

```

---

### Scilab code Exa 3.8 Ratio of vacancies in metal

```

1 // Scilab Code Ex3.8 : Page-3.13 (2004)
2 clc;clear;
3 N = 1; // For simplicity assume total number of
  metal ions to be unity
4 e = 1.6e-019; // Electronic charge, C
5 k = 1.38e-023/e; // Boltzmann constant, eV/K
6 T1 = 500; // First temperature for metal, K
7 T2 = 1000; // Second temperature for metal, K
8 E_v = 1; // Average energy required to create a
  vacancy in metal, eV
9 n_500 = N*exp(-E_v/(k*T1)); // Number of vacancies
  at 500 K
10 n_1000 = N*exp(-E_v/(k*T2)); // Number of vacancies
  at 1000 K
11 n_ratio = n_1000/n_500; // Ratio of vacancies in
  metal
12 printf("\nThe ratio of vacancies in metal = %5.3e",
  n_ratio);

```

```

13
14 // Result
15 // The ratio of vacancies in metal = 1.085e+05

```

---

**Scilab code Exa 3.9** Fraction of vacancy sites in metal

```

1 // Scilab Code Ex3.9 : Page-3.14 (2004)
2 clc;clear;
3 T1 = 500+273; // First temperature for metal, K
4 T2 = 1000+273; // Second temperature for metal, K
5 frac_vac = 1e-010; // n1/N, the fraction of vacancy
   sites at 500 degree celsius
6 e = 1.6e-019; // Electronic charge, C
7 k = 1.38e-023/e; // Boltzmann constant, eV/K
8 // n1 = N*exp(-E_f/(k*T1)); // Number of vacancies
   at 500 K
9 // n2 = N*exp(-E_f/(k*T2)); // Number of vacancies
   at 500 K, solving for n2/N = x
10 x = exp((T1/T2)*log(frac_vac));
11 printf("\\nThe fraction of vacancy sites in metal =
   %6.4e", x);
12
13 // Result
14 // The fraction of vacancy sites in metal = 8.4670e
   -07

```

---

**Scilab code Exa 3.10** Average energy required to create Schottky defect

```

1 // Scilab Code Ex3.10 :Page-3.16 (2004)
2 T = 273+25; // Temperature , K
3 r = 2.82e-10; // Interionic distance, m
4 N = 4/((2*r)^3); // Density of ion pairs, ion
   pairs

```

```

5 k = 8.625e-5; // Boltzmann constant , J/K
6 n = 5e+11; // Density od Schottky effects , per unit
  volume
7 E_s = 2*k*T*2.303*log10(N/n); // Average energy
  required to creat Schottky defect
8 printf("\nAverage energy required to create Schottky
  defect = %5.3f eV", E_s);
9
10 // Result
11 // Average energy required to create Schottky defect
  = 1.971 eV

```

---

**Scilab code Exa 3.11** Ratio of vacancies in metal to create Frenkel defect

```

1 // Scilab Code Ex3.11 : Ratio of vacancies in metal
  to create Frenkel defect:Page-3.18 (2004)
2 N = 1; // For simplicity assume total number of
  metal ions to be unity
3 Ni = 1; // For simplicity assume total number of
  metal ions to be unity
4 k = 8.625e-5; // Boltzmann constant , J/K
5 T1 = 273+20; // First temperature for metal, K
6 T2 = 300+273; // Second temperature for metal, K
7 E_v = 1.4; // Average energy required to create a
  vacancy in metal, eV
8 n_293 = N*exp(-E_v/(2*k*T1)); // Number of
  vacancies at 500 K
9 n_573 = N*exp(-E_v/(2*k*T2)); // Number of
  vacancies at 500 K
10 n_ratio1 = n_573/n_293; // Ratio of vacancies in
  metal
11 n_ratio2 = n_293/n_573; // Ratio of vacancies in
  metal
12
13 printf("\nThe ratio 1 of vacancies in metal to

```

```
    create Frenkel defect = %5.3e", n_ratio1);
14 printf("\nThe ratio 2 of vacancies in metal to
    create Frenkel defect = %5.3e", n_ratio2);
15
16 // Result
17 // The ratio 1 of vacancies in metal to create
    Frenkel defect = 7.558e+05
18 // The ratio 2 of vacancies in metal to create
    Frenkel defect = 1.323e-06
```

---



## Chapter 4

# Line Defects and Crystal Structure Determination

Scilab code Exa 4.1 Wavelength of X ray and order of diffraction

```
1 // Scilab Code Ex4.1 : Page-4.13 (2004)
2 clc;clear;
3 function thet = degree_minute (d, m)
4     thet = d + m/60;
5 endfunction
6 deg = 8, minutes = 35; // Given glancing angle ,
    degrees-minutes
7 theta = degree_minute (deg, minutes); // Convert
    degree-minutes to degrees
8 d = 0.282; // lattice spacing for NaCl crystal ,
    nm
9 n = 1; // Order of diffraction
10 lambda = 2*d*sind(theta)/n; // Wavelength from
    Bragg's law, nm
11 printf("\nWavelength of X rays = %6.4f nm ", lambda)
    ;
12 theta = 90; // maximum possible value for theta for
    maximum order of diffraction
13 n = 2*d*sind(theta)/lambda; // order of diffraction
```

```

    from Bragg's law
14 printf("\nMaximum possible order of diffraction =
    %1d", n);
15
16 // Result
17 // Wavelength of X rays = 0.0842 nm
18 // Maximum possible order of diffraction = 6

```

---

**Scilab code Exa 4.2** Ratio of interplanar spacing in simple cube

```

1 // Scilab Code Ex4.2 : Page-4.13 (2004)
2 clc;clear;
3 a = 1; // For simplicity we assume a to be unity,
    unit
4 h1 = 1, k1 = 0, l1 = 0; // Indices of first set
    of parallel planes
5 d_100 = a/sqrt(h1^2 + k1^2 + l1^2); //
    Interplanar spacing for (100) planes, unit
6 h2 = 1, k2 = 1, l2 = 0; // Indices of second set
    of parallel planes
7 d_110 = a/sqrt(h2^2 + k2^2 + l2^2); //
    Interplanar spacing for (110) planes, unit
8 h3 = 1, k3 = 1, l3 = 1; // Indices of third set
    of parallel planes
9 d_111 = a/sqrt(h3^2 + k3^2 + l3^2); //
    Interplanar spacing for (111) planes, unit
10 printf("\nd_100 : d_110 : d_111 = %1d : %4.2f : %4.2
    f", d_100, d_110, d_111);
11
12 // Result
13 // d_100 : d_110 : d_111 = 1 : 0.71 : 0.58

```

---

**Scilab code Exa 4.3** Wavelength of X ray from Bragg Law

```

1 // Scilab Code Ex4.3 : Page-4.14 (2004)
2 clc;clear;
3 function thet = degree_minute (d, m)
4     thet = d + m/60;
5 endfunction
6
7 degr = 8, minutes = 35; // Given glancing angle ,
    degrees-minutes
8 theta = degree_minute (degr, minutes); // Convert
    degree-minutes to degrees
9 d = 0.282; // lattice spacing for NaCl crystal ,
    nm
10 n = 1; // Order of diffraction
11 lambda = 2*d*sind(theta)/n; // Wavelength from
    Bragg's law , nm
12
13 printf("\nWavelength of X rays = %6.4f nm ", lambda)
    ;
14
15 // Result
16 // Wavelength of X rays = 0.0842 nm

```

---

#### Scilab code Exa 4.4 Interatomic spacing

```

1 // Scilab Code Ex4.4 : Page-4.14 (2004)
2 clc;clear;
3 theta = 30; // bragg's angle , degree
4 lambda = 1.5418e-10; // X-ray wavelength , m
5 n = 1; // Order of diffraction
6 d = (n*lambda)/(2*sind(theta)); // Wavelength from
    Bragg's law , nm
7 h = 1, k = 1, l = 1; // plane
8 a = d*(h^2+k^2+l^2)^(1/2); // interatomic spacing ,
    angstrom
9 printf("\nWavelength of X rays = %6.4e m ", d);

```

```

10 printf("\nInteratomic spacing = %5.3f angstrom", a/1
    e-10);
11
12 // Result
13 // Wavelength of X rays = 1.5418e-10 m
14 // Interatomic spacing = 2.670 angstrom

```

---

**Scilab code Exa 4.5** Glancing angle for second order diffraction

```

1 // Scilab Code Ex4.5 : Page-4.14 (2004)
2 clc;clear;
3 lambda = 0.071; // X-ray wavelength, nm
4 n = 2; // Second order of diffraction
5 d_100 = 0.28; // Interplanar spacing for (100)
    plane, nm
6 d_110 = d_100/sqrt(2); // Interplanar spacing for
    (110) plane, nm
7 x = n*lambda/(2*d_110); // sine of angle, degree
8 theta = asind(x); // Glancing angle for second
    order diffraction
9
10 printf("\nGlancing angle for second order
    diffraction = %d degree ", round(theta));
11
12 // Result
13 // Glancing angle for second order diffraction = 21
    degree

```

---

**Scilab code Exa 4.6** Distance between two adjacent atoms in NaCl

```

1 // Scilab Code Ex4.6 : Page-4.15 (2004)
2 clc;clear;
3 n = 4; // Second order of diffraction

```

```

4 M = 58.5;    // Molecular weight of crystal
5 d = 2180;   // Density of crystal , kg per cm cube
6 N = 6.02e+26; // Avogadro number , k / mol
7 a = ((n*M)/(d*N))^(1/3); // Distance between two
    adjacent atoms of same kind , nm
8 b = a/2;    // Distance between two adjacent atoms
    of different kind , nm
9 printf("\nDistance between two adjacent atoms of
    same kind = %5.3f nm ", a/1e-9);
10 printf("\nDistance between two adjacent atoms of
    different kind = %5.3f nm ", b/1e-9);
11 // Result
12
13 // Distance between two adjacent atoms of same kind
    = 0.563 nm
14 // Distance between two adjacent atoms of different
    kind = 0.281 nm

```

---

**Scilab code Exa 4.7** Distance between 110 plane

```

1 // Scilab Code Ex4.7 Page-4.16 (2004)
2 clc;clear;
3 a = 0.38; // Lattice constant of copper , nm
4 h =1, k = 1, l = 0; // Miller Indices (hkl)= (110)
5 d = a/sqrt(h^2 + k^2 + l^2); // Interplanar
    spacing for (110) plane , unit
6 printf("\nInterplanar spacing for (110) plane = %4.2
    f nm", d);
7
8 // Result
9 // Interplanar spacing for (110) plane = 0.27 nm

```

---

**Scilab code Exa 4.8** Density of Iron

```
1 // Scilab Code Ex4.8 : Page-4.16 (2004)
2 clc;clear;
3 r = 0.123e-9; // Atomic radius of iron , m
4 n = 4; // Second order of diffraction
5 M = 55.8; // Molecular weight of crystal
6 a = 2*r*sqrt(2); // lattice constant , m
7 N = 6.023e+26; // Avogadro number , k / mol
8 d = n*M/(N*a^3); // Density of iron , kg /m-cube
9 printf("\\nDensity of iron = %5.4d kg/metrecube ", d)
;
10
11 // Result
12 // Density of iron = 8800 kg/metrecube
```

---

# Chapter 5

## Principles of Quantum Mechanics

Scilab code Exa 5.1 de Broglie wavelength of proton

```
1 // Scilab Code Ex5.1 : Page-5.7 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const in Js
4 m = 1.67e-27; // Mass of the proton in kg
5 c = 3e+8; // Charge of electron in C
6 v = c/10; // Proton velocity 1/10th of c
7 E = 0.025; // Kinetic energy of the neutron in J
8 lam = h/(m*v); // de Broglie wavelength in m
9 printf("\nde Broglie wavelength = %5.3e m", lam);
10
11 // Result
12 // de Broglie wavelength = 1.323e-14 m
```

---

Scilab code Exa 5.2 de Broglie wavelength of electron

```
1 // Scilab Code Ex5.2 : de Broglie wavelength of
  electron: Page-5.8 (2004)
```

```

2 clc;clear;
3 V = 400; // Accelerating potential , volts
4 lam = 12.26/sqrt(V); // de Broglie wavelength ,
    angstrom
5 printf("\\nde Broglie wavelength = %5.3f angstrom",
    lam);
6
7 // Result
8 // de Broglie wavelength = 0.613 angstrom

```

---

**Scilab code Exa 5.3** de Broglie wavelength of neutron

```

1 // Scilab Code Ex5.3 : Page-5.8 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const in Js
4 m = 1.67e-27; // Mass of the neutron in kg
5 e = 1.6e-19; // charge of electron in C
6 E = 0.025; // kinetic energy of the neutron in J
7 lam = h/(sqrt(2*m*E*e)); // de Broglie wavelength
    in m
8 printf("\\nde Broglie wavelength = %5.3f nm", lam/1e
    -9);
9
10 // Result
11 // de Broglie wavelength = 0.181 nm

```

---

**Scilab code Exa 5.4** Uncertainty in momentum of electron

```

1 // Scilab Code Ex5.4 : Uncertainty in momentum of
    electron: Page-5.13 (2004)
2 clc;clear;
3 h = 6.62e-34 // Planck's const , Js
4 delx = 4e-10 // Uncertainty in position , m

```



```

5 delp = h/(delx); // Uncertainty principle
6
7 printf("\nUncertainty in momentum = %5.3e kg m/sec",
      delp);
8
9 //Results
10 // Uncertainty in momentum = 1.655000e-24 kg m/sec

```

---

### Scilab code Exa 5.5 Uncertainty in velocity of electron

```

1 // Scilab Code Ex5.5 : Page-5.13 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's const, Js
4 me = 9.1e-31; //Mass of electron, kg
5 delx = 1e-9; // Uncertainty in position, m
6 delp = h/(delx); // Uncertainty principle
7 delv = (delp/me); // Uncertainty in velocity, m/sec
8
9 printf("\nUncertainty in velocity = %4.2e m/sec",
      delv)
10
11 // Result
12 // Uncertainty in velocity=7.2747e+05 m/sec

```

---

### Scilab code Exa 5.6 Uncertainty in time

```

1 // Scilab Code Ex 5.6 : Uncertainty in time : Page
  -5.13 (2004)
2 clc;clear;
3 h = 6.62e-34; // planck's const, Js
4 n1 = 1; // first state
5 n2 = 2; // second state

```

```

6 En = (-13.6/n2^2)+(13.6/n1); //Energy for
   transition , in eV
7 e = 1.6e-19; // Charge of electron , C
8 E2 = e*En; // Energy for transition , J
9 delE = E2/100; // Uncertainty in position , m
10 delT = h/(delE); // Uncertainty principle
11 printf("\nUncertainty in time = %1.3e sec", delT);
12
13 // Results
14 // Uncertainty in time = 4.056e-14 sec

```

---

**Scilab code Exa 5.7** Lowest Energy for electron confinement

```

1 // Scilab Code Ex 5.7 : Lowest Energy for electron
   confinement: Page-5.22 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's const , Js
4 m = 9.1e-31; // Mass of electron in kg
5 L = 0.1e-9; // Side of the box in m
6 n1 = 1; // nx box lowest quantum number
7 n2 = 1; // ny box lowest quantum number
8 n3 = 1; // nz box lowest quantum number
9 e = 1.6e-19; // Charge on electron in C
10 E = (h^2)/(8*e*m*L^2)*((n1)^2+(n2)^2+(n3)^2); //
   Lowest Energy for electron confinement , in eV
11 printf("\nLowest Energy for electron confinement =
   %5.1f eV", E);
12
13
14 // Results
15 // Lowest Energy for electron confinement = 112.9 eV

```

---

**Scilab code Exa 5.8** Next Lowest Energy level for electron confinement

```

1 // Scilab Code Ex 5.8 : Page-5.22 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's constant, Js
4 m = 9.1e-31; // Mass of electron, kg
5 L = 0.1e-9; // Side of the box, m
6 n1 = 1; // nx box lowest quantum number
7 n2 = 1; // ny box lowest quantum number
8 n3 = 2; // nz box lowest quantum number
9 e = 1.6e-19; // Charge on electron, C
10 E = (h^2)/(8*e*m*L^2)*((n1)^2+(n2)^2+(n3)^2); //
    Lowest Energy level for electron confinement, in
    eV
11
12 printf("\nLowest Energy level for electron
    confinement = %6.2f eV", E);
13
14 // Result
15 // Lowest Energy level for electron confinement =
    225.74 eV

```

---

**Scilab code Exa 5.9** de Broglie wavelength from energy

```

1 // Scilab Code Ex5.9 : Page-5.23 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const in Js
4 m = 9.1e-31; // Mass of the neutron in kg
5 e = 1.6e-19; // Charge of electron in C
6 E = 2000; // Kinetic energy of the neutron in eV
7 lam = h/(sqrt(2*m*E*e)); // de Broglie wavelength
    in m
8 printf("\nde Broglie wavelength of electron = %6.4f
    nm", lam/1e-9);
9
10 // Result
11 // de Broglie wavelength of electron = 0.0275 nm

```

---

**Scilab code Exa 5.10** Minimum Energy

```
1 // Scilab Code Ex 5.10 : Page-5.24 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const , Js
4 m = 9.1e-31; // Mass of electron , kg
5 L = 4e-10; // Side of the box, m
6 n1 = 1; // nx box lowest quantum number
7 E = (h^2)/(8*m*(L^2))*((n1)^2); //Lowest Energy
   level for electron confinement , in eV
8 printf("\nMinimum Energy = %2.3e joule", E);
9
10 // Results
11 // Minimum Energy = 3.769e-19 joule
```

---

**Scilab code Exa 5.11** Energy of ground and first and second state

```
1 // Scilab Code Ex 5.11 : Page-5.24 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const , Js
4 m = 9.1e-31; // Mass of electron in kg
5 L = 1e-10; // Side of the box in m
6 n1 = 1; // Ground state quantum number
7 n2 = 2; // first quantum number
8 n3 = 3; // second quantum number
9 e = 1.6e-19; // charge on electron , C
10 E1 = (h^2)/(8*m*(L^2))*((n1)^2); //Ground state
   Energy , joule
11 E2 = (h^2)/(8*m*(L^2))*((n2)^2); //first state
   Energy , joule
12 E3 = (h^2)/(8*m*(L^2))*((n3)^2); //second state
   Energy , joule
```

```

13
14 printf("\nGround state Energy = %2.3e joule", E1);
15 printf("\nFirst state Energy = %2.3e joule", E2);
16 printf("\nSecond state Energy = %2.3e joule", E3);
17
18
19 // Results
20 // Ground state Energy = 6.031e-18 joule
21 // First state Energy = 2.412e-17 joule
22 // Second state Energy = 5.428e-17 joule

```

---

**Scilab code Exa 5.12** Velocity and energy of electron

```

1 // Scilab Code Ex5.12 : Page-5.25 (2004)
2 clc;clear;
3 h = 6.626e-34; // Planck's const in Js
4 m = 9.1e-31; // Mass of the electron in kg
5 lam = 1.66e-10; // de Broglie wavelength, m
6 e = 1.6e-19; // Charge on electron, C
7 v = h/(m*lam); // Velocity of electron, m/s
8 E = (m*v^2)/(2*e); // Kinetic energy of the
    electron in eV
9
10 printf("\nVelocity of electron = %d km/s", v/1000);
11 printf("\nKinetic energy of the electron = %5.2f eV"
    , E);
12
13 // Result
14 // Velocity of electron = 4386 km/s
15 // Kinetic energy of the electron = 54.71 eV

```

---

**Scilab code Exa 5.13** Wavelength of electron waves

```

1 // Scilab Code Ex5.13 : Page-5.25 (2004)
2 clc; clear;
3 V = 15000; // Accelerating potential, volts
4 lam = 12.26/sqrt(V); // de Broglie wavelength,
   angstrom
5 printf("\\nde Broglie wavelength of electron wave =
   %5.1f angstrom", lam);
6
7 // Result
8 // de Broglie wavelength of electron wave = 0.1
   angstrom

```

---

**Scilab code Exa 5.14** Uncertainty in momentum of electron

```

1 // Scilab Code Ex5.14 : Page-5.26 (2004)
2 clc; clear;
3 h = 6.62e-34 // Planck's const, Js
4 delx = 1e-8 // Uncertainty in position, m
5 m = 9.1e-31; // Mass of electron, kg
6 delv = h/(m*delx); // Uncertainty in velocity, km/s
7
8 printf("\\nUncertainty in velocity = %3.2f km/sec",
   delv/1000);
9
10 //Results
11 // Uncertainty in velocity = 72.75 km/sec

```

---

# Chapter 6

## Electron Theory of Metals

Scilab code Exa 6.1 Electron Density and mobility in silver

```
1 // Scilab Code Ex6.1 : Page-6.8 (2004)
2 clc;clear;
3 M = 107.9; // Molecular weight of silver , kg
4 d = 10.5e+03; // Density of of silver , kg per
    metrecube
5 N = 6.023D+26; // Avogadro's Number., atoms/k-mol
6 a = 6.8e+07; // conductivity of silver , per ohm
    per sec
7 e = 1.6e-19; // charge of electron , C
8 n = d*N/M; // Density of electron
9 mu = a/(n*e); // Mobility of electron
10 printf("\nDensity of electron = %4.2e ", n);
11 printf("\nMobility of electron = %5.3e metersquare
    per volt per sec", mu);
12
13 // Result
14 // Density of electron = 5.86e+28
15 // Mobility of electron = 7.251e-03 metersquare per
    volt per sec
```

---

**Scilab code Exa 6.2** Mobility and average time of collision in copper

```
1 // Scilab Code Ex6.2 : Page-6.9 (2004)
2 clc;clear;
3 M = 63.5; // Molecular weight of copper , kg
4 d = 8.92e+03; // Density of of copper , kg per
    metrecube
5 rho = 1.73e-8; // Resistivity of copper , ohm m
6 m = 9.1e-31; // Mass of electron , kg
7 N = 6.023D+26; // Avogadro 's No. , atoms/k-mol
8 e = 1.6e-19; // Charge of electron , C
9 n = d*N/M; // Density of electron
10 mu = 1/(rho*n*e); // Mobility of electron
11 t = m/(n*(e^2)*rho); // Average time of collision
    , sec
12 printf("\nNumber Density of electron = %4.2e ", n);
13 printf("\nMobility of electron = %3.3e meter per
    volt per sec", mu);
14 printf("\naverage time of collision = %3.2e sec", t)
    ;
15
16 // Result
17 // Number Density of electron = 8.46e+28
18 // Mobility of electron = 4.270e-03 meter per volt
    per sec
19 // average time of collision = 2.429e-14 sec
```

---

**Scilab code Exa 6.3** Electrical resistivity in Sodium metal

```
1 // Scilab Code Ex6.3 : Page-6.10 (2004)
2 clc;clear;
3 t = 3e-14; // Mean free time , sec
```



```

4 m = 9.1e-31;    // Mass of electron , kg
5 e = 1.6e-19;   // Charge of electron , C
6 r = 1.85e-10;  // Radius of sodium atom, m
7 a = 4*r/sqrt(3); // Sodium has BCC structure
8 n = 2/(a^3);   // Number of electron per unit volume
9 rho = m/(n*(e^2)*t); // Electrical resistivity ,
    ohm m
10
11 printf("\nElectrical resistivity = %3.3e ohm m",
    rho);
12
13 // Result
14 // Electrical resistivity = 4.620e-08 ohm m

```

---

#### Scilab code Exa 6.4 Resistivity of sodium at zero degree Celsius

```

1 // Scilab Code Ex6.4: Page-6.11 (2004)
2 clc;clear;
3 t = 3.1e-14; // Mean free time, sec
4 m = 9.1e-31; // Mass of electron , kg
5 e = 1.6e-19; // Charge of electron , C
6 r = 0.429e-9; // Side of the unit cell. m
7 n = 2/(r^3); // Number of electron per unit
    cubemetre
8 rho = m/(n*(e^2)*t); // Electrical resistivity ,
    ohm m
9 printf("\nElectrical resistivity of sodium at zero
    degree Celsius = %2.3e ohm m", rho);
10
11 // Result
12 // Electrical resistivity of sodium at zero degree
    Celsius = 4.527e-08 ohm m

```

---

**Scilab code Exa 6.5** Next Lowest Energy level for electron confinement

```
1 // Scilab Code Ex 6.5 : Page-6.15 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's const, Js
4 m = 9.1e-31; // Mass of electron in kg
5 L = 0.1e-9; // Side of the box in m
6 n1 = 1; // nx box lowest quantum number
7 n2 = 1; // ny box lowest quantum number
8 n3 = 1; // nz box lowest quantum number
9 e = 1.6e-19; // Charge on electron, C
10 E = (h^2)/(8*e*m*L^2)*((n1)^2+(n2)^2+(n3)^2); //
    Lowest Energy level for electron confinement, in
    eV
11 printf("\nLowest Energy level for electron
    confinement = %2.1f eV", E);
12
13 // Results
14 // Lowest Energy level for electron confinement =
    112.9 eV
```

---

**Scilab code Exa 6.7** Energy level for electron confinement and equivalent temperature

```
1 // Scilab Code Ex 6.7: Page-6.17 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's const, Js
4 m = 9.1e-31; // Mass of electron in kg
5 L = 1e-9; // length of cube box, m
6 n1 = 1; // nx box quantum number
7 n2 = 1; // ny box lowest quantum number
8 n3 = 2; // nz box quantum number
9 k = 1.38e-23; // Boltzmann constant, joule
    per kelvin
10 e = 1.6e-19; // Charge on electron, C
```

```

11 E = (h^2)/(8*m*L^2)*((n1)^2+(n2)^2+(n3)^2); //
    Lowest Energy level for electron confinement , in
    joule
12 T = 2*E/(3*k); // Equivalent temperature of the
    molecules , kelvin
13
14 printf("\nEnergy for electron confinement = %5.3e
    joule", E);
15 printf("\nEquivalent temperature of the molecules =
    %5.3e kelvin", T);
16
17 // Results
18 // Energy for electron confinement = 3.61e-19 joule
19 // Equivalent temperature of the molecules = 1.74e
    +04 kelvin

```

---

#### Scilab code Exa 6.9 Temperature from Fermi function

```

1 // Scilab Code Ex 6.9: Page-6.18 (2004)
2 clc;clear;
3 k = 1.38e-23; // Boltzmann constant , joule
    per kelvin
4 T = 300; // For simplicity room temperature is
    taken , kelvin
5 e = 1.6e-19; // Charge on electron , C
6 E = k*T; // Given Energy , eV
7 F_E = 1/(1+exp(E/(k*T))); //Fermi function ,
    unitless
8 T = 300; // For simplicity room temperature is
    taken , kelvin
9 printf("\nFermi fucntion = %5.3f ", F_E);
10
11 // Results
12 // Fermi fucntion = 0.269

```

---

**Scilab code Exa 6.10** Temperature for occupation of a state above Fermi level

```
1 // Scilab Code Ex 6.10: Page-6.18 (2004)
2 clc;clear;
3 k = 1.38e-23; // Boltzmann constant, joule
  per kelvin
4 T = 300; // For simplicity room temperature is
  taken, kelvin
5 e = 1.6e-19; // Charge on electron, C
6 EF = 5.5; // Fermi Energy, eV
7 E = EF+(EF/100); // New energy, eV
8 F_E = 0.1; // Fermi function, unitless
9 T = e*(E-EF)/(k*log((1-F_E)/F_E)); //Temperature
  for 10% probabilty that electron in silver have
  an energy 1% above the fermi energy, kelvin
10
11 printf("\nTemperature = %5.1f kelvin", T);
12
13 // Results
14 // Temperature = 290.2 kelvin
```

---

**Scilab code Exa 6.11** Number of energy state in unit volume

```
1 // Scilab Code Ex 6.11: Page-6.22 (2004)
2 clc;clear;
3 h = 6.62e-34; // Planck's constant, Js
4 m = 9.14e-31; // Mass of the electron, kg
5 e = 1.6e-19; // Charge on electron, C
6 E1=3.22*e; // First state energy, joules
7 E2=3.24*e; // Second state energy, joules
```

```

8 n = 8*pi*(2*m)^(3/2)*(E2^(3/2)-E1^(3/2))/(3*h^3);
    // Number of energy state in unit volume
9
10 printf("\nNumber of energy state in unit volume= %4
    .3e ", n);
11
12 //Result
13 // Number of energy state in unit volume= 2.463e+26

```

---

**Scilab code Exa 6.12** Temperature needed to fill a state above Fermi level

```

1 // Scilab Code Ex 6.12: Page-6.22 (2004)
2 clc;clear;
3 k = 1.38e-23; // Boltzmann constant, joule
    per kelvin
4 T = 300; // For simplicity room temperature is
    taken, kelvin
5 e = 1.6e-19; // Charge on electron, C
6 EF = 1; // For simplicity Fermi Energy is taken
    as unity, eV
7 E = EF+0.5; // New energy, eV
8 F_E = 0.01; // Fermi function, unitless
9 T = e*(E-EF)/(k*log((1-F_E)/F_E)); //Temperature
    for 1% probability that electron have an energy
    0.5eV above the fermi energy, kelvin
10
11 printf("\nTemperature = %d kelvin", round(T));
12
13 // Results
14 // Temperature = 1262 kelvin

```

---

# Chapter 7

## Dielectric Properties

Scilab code Exa 7.1 Net energy stored in capacitor

```
1 // Scilab Code Ex7.1: Page-7.23 (2004)
2 clc; clear;
3 C = 2e-6; // Capacitance , farad
4 V = 1000; // Applied Voltage , volt
5 W = C*V^2/2; // Energy stored in capacitor , joule
6 er = 100; // Electric permittivity
7 Co = C/er; // New Capacitance without dielectric ,
  farad
8 Wo = Co*V^2/2; // New Energy without dielectric ,
  farad
9 Wt = W-Wo; // Net energy stored in capacitor ,
  joules
10 printf("\\nNet energy stored in capacitor = %3.2f
  joules", Wt);
11
12 // Result
13 // Net energy stored in capacitor = 0.99 joules
```

---

Scilab code Exa 7.2 Ratio of polarization

```

1 // Scilab Code Ex7.2: Page-7.24 (2004)
2 clc;clear;
3 er = 4.94; //Electric permittivity
4 n = sqrt(2.69); // Index of refraction, unitless
5 a = (n^2-1)/(n^2+2); // Variable 1
6 b = (er-1)/(er+2); // Variable 2
7 alpha = (b/a)-1; // Ratio between ionic and
    electrical polarization
8 alp = 1/alpha; //Ratio between electrical and
    ionic polarization
9
10 printf("\nRatio between ionic and electrical
    polarization = %3.3f ", alpha);
11 printf("\nRatio between electrical and ionic
    polarization = %3.3f ", alp);
12
13 // Result
14 // Ratio between ionic and electrical polarization
    = 0.576
15 // Ratio between electrical and ionic polarization
    = 1.738

```

---

### Scilab code Exa 7.3 Parallel loss resistance and capacitance

```

1 // Scilab Code Ex7.3: Page-7.25 (2004)
2 clear;clc;
3 er = 2.56; // Relative permittivity
4 tan_delta = 0.7e-4; // Loss tangent
5 f = 1e+6; // frequency, Hz
6 er2 = er*tan_delta; // Imaginary part of relative
    permittivity
7 A = 8e-4; // Area between plates, squaremetre
8 eo = 8.854e-12; //Permittivity of the free space,
    farad per metre
9 w = 2*pi*f; // angular frequency, Hz

```

```

10 d = 0.08e-3;    // Distance between plates , m
11 Rp = d/(w*eo*er2*A);    // Parallel loss resistance ,
    ohm
12 Cp = A*eo*er/d;    // Capacitance , farad
13
14 printf("\nParallel loss resistance = %3.3e ohm", Rp)
    ;
15 printf("\nCapacitance = %3.3e farad", Cp);
16
17 // Result
18 //Parallel loss resistance = 1.003e+07 ohm
19 //Capacitance = 2.267e-10 farad

```

---

#### Scilab code Exa 7.4 Dielectric constant of the material

```

1 // Scilab Code Ex7.4: Page-7.26 (2004)
2 clc;clear;
3 N = 3e+28;    // Number density , atoms per metrecube
4 eo = 8.854e-12; //Permittivity of the free space ,
    farad per metre
5 alpha = 10e-40;    // Electrical polarization , farad
    metresquare
6 er = 1+(N*alpha/eo);    // Dielectric constant of
    the material
7 printf("\nDielectric constant of the material = %3.3
    f ", er);
8
9
10 // Result
11 // Dielectric constant of the material = 4.388

```

---

#### Scilab code Exa 7.5 Electric polarizability of He atoms



```

1 // Scilab Code Ex7.5: Page-7.26 (2004)
2 clc;clear;
3 N = 2.7e+25; // Number density, atoms per
    metre cube
4 eo = 8.854e-12; // Permittivity of the free space,
    farad per metre
5 er = 1.0000684; // Dielectric constant of the
    material
6 alpha = eo*(er-1)/N; // Electrical polarization,
    farad metresquare
7
8 printf("\nElectrical polarization = %3.3e farad
    metresquare", alpha);
9
10 // Result
11 // Electrical polarization = 2.243e-41 farad
    metresquare

```

---

### Scilab code Exa 7.6 Capacitance and charge on the plates

```

1 // Scilab Code Ex7.6: Page-7.27 (2004)
2 clc;clear;
3 A = 100e-4; // Area of parallel plates,
    square metre
4 d = 1e-2; // Distance between plates, metre
5 eo = 8.854e-12; // Permittivity of the free space,
    farad per metre
6 V = 100; // Potential, volt
7 C = eo*A/d; // Capacitance, farad
8 Q = C*V; // Charge on the plates of capacitor
    , C
9 printf("\nCapacitance = %5.3e F ", C);
10 printf("\nCharge on the plates of capacitor = %3.3e
    C", Q);
11

```

```
12 // Result
13 // Capacitance = 8.854e-12 F
14 // Charge on the plates of capacitor = 8.854e-10 C
```

---

**Scilab code Exa 7.7** Electric polarizability of sulphur atoms

```
1 // Scilab Code Ex7.7: Page-7.28 (2004)
2 clc;clear;
3 N = 385.66e+26; // Number density, atoms per
   metrecube
4 eo = 8.854e-12; //Permittivity of the free space,
   farad per metre
5 er = 3.75; // Dielectric constant of the material
6 alpha = 3*eo*(er-1)/(N*(er+2)); // Electric
   polarizability of sulphur atoms
7 printf("\\nElectric polarizability of sulphur atoms =
   %3.3e farad metresquare", alpha);
8
9 // Result
10 // Electric polarizability of sulphur atoms = 3.294
   e-40 farad metresquare
```

---

# Chapter 8

## Magnetic Properties

Scilab code Exa 8.1 Relative permeability

```
1 // Scilab Code Ex8.1: Page-8.33 (2004)
2 clc; clear;
3 M = 3300; // Magnetization of ferromagnetic
   material, amp/metre
4 H = 220; // Magnetic field strength, amp/metre
5 mu_r = M/H+1; // Relative permeability, unitless
6 printf("\\nRelative permeability = %d", mu_r);
7
8 // Result
9 // Relative permeability = 16
```

---

Scilab code Exa 8.2 Magnetization and flux density of ferromagnetic material

```
1 // Scilab Code Ex8.2: Page-8.33 (2004)
2 clc; clear;
3 H = 10^6; // Magnetic field strength, amp/metre
4 ki = 1.5e-3; // Magnetic susceptibility, units
```

```

5 M = ki*H;    // Magnetization of ferromagnetic
   material , amp/metre
6 muo = 4*%pi*1e-7;    // Magnetic permeability , henry
   /metre
7 B = muo*(M+H);    // Flux density , tesla
8 printf("\nMagnetization of ferromagnetic material , =
   %3.1e amp/metre" , M);
9 printf("\nFlux density of ferromagnetic material , =
   %5.3f tesla" , B);
10
11 // Result
12
13 // Magnetization of ferromagnetic material , = 1.5e
   +03 amp/metre
14 // Flux density of ferromagnetic material , = 1.259
   tesla

```

---

### Scilab code Exa 8.3 Magnetization and flux density

```

1 // Scilab Code Ex8.3 : Page-8.34 (2004)
2 clc;clear;
3 H = 10^4;    // Magnetic field strength , amp/metre
4 ki = 3.7e-3;    // Magnetic susceptibility , units
5 M = ki*H;    // Magnetization of ferromagnetic
   material , amp/metre
6 muo = 4*%pi*1e-7;    // Magnetic perbeability , henry
   /metre
7 B = muo*(M+H);    // Flux density , weber/square meter
8 printf("\nMagnetization of ferromagnetic material , =
   %d amp/metre" , M);
9 printf("\nFlux density of ferromagnetic material , =
   %3.4f weber/squaremetre " , B);
10
11 // Result
12

```

```

13 // Magnetization of ferromagnetic material, = 37
    amp/metre
14 // Flux density of ferromagnetic material, = 0.0126
    weber/squaremetre

```

---

#### Scilab code Exa 8.4 Magnetic moment

```

1 // Scilab Code Ex8.4: Page-8.34 (2004)
2 clc; clear;
3 d = 8906; // Density of nickel, kg metrecube
4 An = 6.025e+26; // Avogadro number, per kmol
5 W = 58.7; // Atomic weight, kg
6 N = d*An/W; // Number of nickel atom, per cubemetre
7 Bs = 0.65; // Saturation magnetic, weber per
    squaremetre
8 muo = (4*%pi*1e-7); // Magnetic perbeability,
    henry/metre
9 mum = Bs/(N*muo); // Magnetic moment, ampere per
    sqauemetre
10 X = mum/(9.27e-24); // magnetic moment, bohr
    magneton
11
12 printf("\\nNumber of nickel atom per cubemetre = %3.3
    e /cubemetre", N);
13 printf("\\nMagnetic moment = %1.2e bohr magneton", X)
    ;
14
15 // Result
16
17 // Number of nickel atom per cubemetre = 9.141e+28
    /cubemetre
18 // Magnetic moment = 6.10e-01 bohr magneton

```

---

### Scilab code Exa 8.5 Calculation of temperature using classical statistics

```
1 // Scilab Code Ex8.5: Page –8.35 (2004)
2 clc;clear;
3 mu = 9.4e-24; // Magnetic moment, ampere metre
    square
4 H = 2; // Magnetic field , weber per squaremetre
5 k = 1.38e-23; // Boltzmann Constant, joule per
    kelvin
6 T = (2*mu*H)/(log(2)*k); //Temperature using
    classical statistics , K
7
8 printf("\nTemperature using classical statistics =
    %3.1f K", T);
9
10 // Result
11 // Temperature using classical statistics = 3.9 K
```

---

### Scilab code Exa 8.6 Saturation magnetization

```
1 // Scilab Code Ex8.6: Page –8.36 (2004)
2 clc;clear;
3 A = 6.025e+26; // Avogadro number, per k mol
4 W = 157.26; // Atomic weight, kg
5 d = 7.8e+3; // Density of nickel,kg metrecube
6 N = d*A/(W*1000); // No of atoms, per gm metrecube
7 muo = 4*pi*1e-7; // Magnetic perbeability, henry
    per m
8 mum = N*7.1*(9.27e-24); // Magnetic moment, ampere
    metersquare
9 Bs = mum*muo; // Saturation magnetization, weber/
    squaremetre
10 printf("\nMagnetic moment = %6.4e ampere meter
    square", mum);
11 printf("\nSaturation magnetization = %6.4e weber/
```

```

    squaremetre", Bs);
12
13 // Result
14 // Magnetic moment = 1.9669e+03 ampere meter square
15 // Saturation magnetization = 2.4716e-03 weber/
    squaremetre

```

---

### Scilab code Exa 8.7 Magnetic moment of nickel in Bohr Magneton

```

1 // Scilab Code Ex8.7: Page-8.36 (2004)
2 clc; clear;
3 d = 8906; // Density of nickel, kg per metrecube
4 An = 6.025e+26; // Avogadro number, per k mol
5 W = 58.7; // Atomic weight, kg
6 N = d*An/W; // Number density of nickel atom, per
    cubemetre
7 Bs = 0.65; // Saturation magnetization, wb per
    squaremetre
8 muo = (4*%pi*1e-7); // magnetic perbeability,
    henry/metre
9 mum = Bs/(N*muo); // magnetic moment, ampere per
    squaremetre
10 X = mum/(9.27e-24); // magnetic moment, bohr
    magneton
11
12 printf("\\nNumber density of nickel atom = %3.3e /
    cubemetre", N);
13 printf("\\nMagnetic moment = %1.2f bohr magneton", X)
    ;
14
15 // Result
16
17 // Number density of nickel atom per cubemetre =
    9.141e+28 /cubemetre
18 // Magnetic moment = 6.10e-01 bohr magneton

```





# Chapter 9

## Semiconductors

Scilab code Exa 9.1 Resistivity

```
1 // Scilab Code Ex9.1: Page-9.24 ; (2004)
2 clc;clear;
3 ni = 2.37e+19; // Carrier concentration at room
   temperature
4 mu_e = 0.38; // mobility of electron; m2V-1s-1
5 e = 1.6e-19; // electronic charge, C
6 mu_h = 0.18; // mobility of holes; m2V-1s-1
7 sigma = ni*e*(mu_e+mu_h); // conductivity, mho.m-1
8 rho = 1/sigma; // Resistivity in Ge, ohm.m
9 printf("\nConductivity in Ge = %4.2f mho.per m",
   sigma);
10 printf("\nResistivity in Ge = %5.3f ohm.m", rho);
11
12 //Results
13 // Conductivity in Ge = 2.12 mho.per m
14 // Resistivity in Ge = 0.471 ohm.m
```

---

Scilab code Exa 9.2 Determination of Fermi level

```

1 // Scilab Code Ex9.2: Page-9.24 (2004)
2 clc;clear;
3 Eg = 1.12; // Bandgap of silicon , eV
4 me = 0.12*9.1e-031; // Effective Mass of the
   electron , kg
5 e = 1.6e-19; // Electronic charge , C
6 mh = 0.28*9.1e-031; // Effective Mass of the hole
   , kg
7 k = 1.38e-23; // Boltzman constant , joule per
   kelvin
8 T = 300; // temperature , K
9 EF = (Eg/2)+3/4*k*T*(log(2.333))/e; // EF = E(Eg/2)
   +3/4*k*T*(log(2.333))/e; Formula
10
11 printf("\nThe position of Fermi Level = %4.3f eV",
   EF);
12
13 // Result
14 // The position of Fermi Level = 0.576 eV

```

---

### Scilab code Exa 9.3 Number of intrinsic carriers at 300K

```

1 // Scilab Code Ex9.3: Number of intrinsic carriers
   at 300K: Page-9.26 ; (2004)
2 clc;clear;
3 e = 1.6e-19; // Electronic charge , C
4 m = 9.1e-31; // Mass of electron , kg
5 T = 300; // Room temperature , K
6 k = 1.38e-23; // Boltzmann Constant , joule per
   kelvin
7 Eg = 0.7*e; // Energy band gap of silicon , J
8 h = 6.626e-34; // Plancks Constant , Js
9 C = 2*(2*%pi*m*k/h^2)^(3/2); // A constant
10 ni = C*T^(3/2)*exp((-Eg)/(2*k*T)); // formula for
   carrier concentration at room temperature

```

```

11 printf("\nNumber of intrinsic carriers at 300K = %3
    .1e per cubemetre ", ni);
12
13 //Results
14 // Number of intrinsic carriers at 300K = 3.3e+19
    per cubemetre

```

---

#### Scilab code Exa 9.4 Resistivity of Ge sample

```

1 // Scilab Code Ex9.4: Page-9.26 ; (2004)
2 clc;clear;
3 ni = 2.4e+19; // Carrier concentration at room
    temperature
4 mu_e = 0.39; // Mobility of electron; m^2V^-1s
    ^-1
5 e = 1.6e-19; // Electronic charge, C
6 mu_h = 0.19; // Mobility of holes, m^2V^-1s^-1
7 sigma = ni*e*(mu_e+mu_h); // Conductivity, mho.m^-1
8 rho = 1/sigma; // Resistivity in Ge, ohm.m
9 printf("\nConductivity in Ge = %4.4f mho.per m",
    sigma);
10 printf("\nResistivity in Ge = %5.3f ohm.m", rho);
11
12
13 //Results
14 // Conductivity in Ge = 2.2272 mho.per m
15 // Resistivity in Ge = 0.449 ohm.m

```

---

#### Scilab code Exa 9.5 Resistance of Ge rod

```

1 // Scilab Code Ex9.5: Page-9.26 ; (2004)
2 clc;clear;

```

```

3 ni = 2.5e+19; // Carrier concentration at room
  temperature
4 mu_e = 0.39; // Mobility of electron; m^2V^-1s
  ^-1
5 e = 1.6e-19; // Electronic charge, C
6 l = 1e-2; // length of Ge rod, m
7 w = 1e-3; // width of Ge rod, m
8 t = 1e-3; // thickness of Ge rod, m
9 A = w*t; // Area of Ge rod, meter square
10 mu_h = 0.19; // Mobility of holes, m^2V^-1s^-1
11 sigma = ni*e*(mu_e+mu_h); // Conductivity, mho.m^-1
12 R = 1/(sigma*A); // Resistivity in Ge, ohm.m
13 printf("\nResistance of Ge rod = %4.2e ohm", R);
14
15 //Results
16 // Resistance of Ge rod = 4.31e+03 ohm

```

---

### Scilab code Exa 9.6 Conductivity of Si

```

1 // Scilab Code Ex9.6: Page-9.27 ; (2004)
2 clc;clear;
3 mu_e = 0.48; // Mobility of electron; m^2V^-1s
  ^-1
4 e = 1.6e-19; // Electronic charge, C
5 m = 9.1e-31; // Mass of electron, kg
6 mu_h = 0.013; // Mobility of holes, m^2V^-1s^-1
7 T = 300; // Room temperature, K
8 k = 1.38e-23; // Boltzmann Constant, joule per
  kelvin
9 Eg = 1.1*e; // Energy band gap of silicon, J
10 h = 6.626e-34; // Plancks Constant, Js
11 C = 2*(2*pi*m*k/h^2)^(3/2); // A constant
12 ni = C*T^(3/2)*exp((-Eg)/(2*k*T)); // formula for
  carrier concentration at room temperature
13 sigma = ni*e*(mu_e+mu_h); // Conductivity, mho per

```

```

    metre
14
15 printf("\nConductivity = %3.1e mho per metre ",
    sigma);
16
17 //Results
18 // Conductivity = 1.2e-03 mho per metre

```

---

**Scilab code Exa 9.7** Electron and hole concentration in silicon

```

1 // Scilab Code Ex9.7: Page -9.27 ; (2004)
2 clc;clear;
3 Na = 5e+23; // Concentration of boron atoms, per
    metre cube
4 Nd = 3e+23; // Concentration of arsenic atoms, per
    metre cube
5 p = Na-Nd; // Hole concentration, per metre cube
6 ni = 2e+16; // Intrinsic concentration, per
    metre cube
7 n = ni^2/p; // Electron concentration, per
    metre cube
8
9 printf("\nHole concentration = %3.1e per metre cube "
    , p);
10 printf("\nElectron concentration = %3.1e per
    metre cube ", n);
11
12 //Results
13 // Hole concentration = 2.0e+23 per metre cube
14 // Electron concentration = 2.0e+09 per metre cube

```

---

**Scilab code Exa 9.8** Temperature that shift the fermi level

```

1 // Scilab Code Ex9.8: Page-9.28 (2004)
2 clc;clear;
3 Eg = 1; // Bandgap of silicon , eV
4 e = 1.6e-19; // Electronic charge , C
5 k = 1.38e-23; // Boltzman constant ,joule per
    kelvin
6 E_F = (0.6-0.5)*e; // Fermi energy , joules
7 // E_F =((Ev+Ec)/2)+3/4*k*T1*(log(4)); // Ev & Ec=
    valance and conduction band energies (formula)
8 T = 4*E_F/(3*k*log(4)); //Temperature that shift the
    fermi level , K
9
10 printf("\\nTemperature that shift the fermi level =
    %4.3d K", T);
11
12 // Result
13 // Temperature that shift the fermi level = 1115 K

```

---

### Scilab code Exa 9.9 Conductivity of intrinsic silicon at 300 K

```

1 // Scilab Code Ex9.9: Page-9.29 ; (2004)
2 clc;clear;
3 ni = 1.5e+16; // Intrinsic Carrier concentration at
    room temperature
4 mu_e = 0.13; // Mobility of electron; m^2V^-1s
    ^-1
5 e = 1.6e-19; // Electronic charge , C
6 Nd = 4.99e+20; // Impurity atoms , per metrecube
7 mu_h = 0.05; // Mobility of holes , m^2V^-1s^-1
8 sigma = ni*e*(mu_e+mu_h); // Conductivity , mho per
    meter
9 sigma_d = Nd*e*mu_e; // Conductivity with donor
    type impurities , mho per meter
10 sigma_a = Nd*e*mu_h; // Conductivity with acceptor
    type impurities , mho per meter

```

```

11 printf("\nConductivity of silicon = %3.2e mho per
    meter", sigma);
12 printf("\nConductivity with donor type impurities =
    %4.2f mho per meter", sigma_d);
13 printf("\nConductivity with acceptor type impurities
    = %4.2f mho per meter", sigma_a);
14
15 //Results
16 // Conductivity of silicon = 4.32e-04 mho per meter
17 // Conductivity with donor type impurities = 10.38
    mho per meter
18 // Conductivity with acceptor type impurities= 3.99
    mho per meter

```

---

**Scilab code Exa 9.10** Conductivity and Position of  $E_f$  above the intrinsic level

```

1 // Scilab Code Ex9.10: Page-9.31 ; (2004)
2 clc;clear;
3 ni = 1.5e+16; // Intrinsic Carrier concentration at
    room temperature
4 mu_e = 0.135; // Mobility of electron; m^2V^-1s
    ^-1
5 e = 1.6e-19; // Electronic charge, C
6 Nd = 1e+23; // Impurity atoms , per metrecube
7 T = 300; // Temperature, Kelvin
8 k = 1.38e-23; // Boltzman constant, joule per
    kelvin
9 mu_h = 0.048; // Mobility of holes , m^2V^-1s^-1
10 sigma = ni*e*(mu_e+mu_h); // Conductivity , mho per
    meter
11 p = ni^2/Nd; // Hole concentration , per metrecube
12 sigma_ex = Nd*e*mu_e; // Conductivity with donor
    type impurities , mho per meter
13 E_F = (3/(4*e))*k*T*(log(0.135/0.048)); // Position

```

```

    of fermi level above the intrinsic level, eV
14 // mu is inversely propotional to mass
15 printf("\nConductivity of silicon = %3.2e mho per
    meter", sigma);
16 printf("\nHole concentration = %4.2e per metrecube",
    p);
17 printf("\nConductivity with donor type impurities =
    %4.2e mho per meter", sigma_ex);
18 printf("\nPosition of fermi level above the
    intrinsic level = %4.2f eV", E_F);
19
20 //Results
21 // Conductivity of silicon = 4.39e-04 mho per meter
22 // Hole concentration = 2.25e+09 per metrecube
23 // Conductivity with donor type impurities = 2.16e
    +03 mho per meter
24 // Position of fermi level above the intrinsic
    level = 0.02 eV

```

---

**Scilab code Exa 9.11** Intrinsic carrier concentration and conductivity in germanium

```

1 // Scilab Code Ex9.11: Page-9.32 ; (2004)
2 clc;clear;
3 e = 1.6e-19; // Electronic charge, C
4 Eg = 0.7*e; // Band gap energy, joules
5 mu_e = 0.4; // Mobility of electron; m^2V^-1s^-1
6 mu_h = 0.2; // Mobility of holes, m^2V^-1s^-1
7 m = 9.1e-31; // Mass of electron, kg
8 h = 6.63e-34; // Plancks Constant, Js
9 T = 300; // Temperature, Kelvin
10 k = 1.38e-23; // Boltzman constant, joule per
    kelvin
11 C = 2*(2*pi*T*m*k/h^2)^(3/2); // Constant parameter
12 ni = C*exp((-Eg)/(2*k*T)); // Carrier

```



```

        concentration at room temperature
13 sigma = ni*e*(mu_e+mu_h); // Conductivity , mho per
    meter
14 printf("\nCarrier concentration at room temperature
    = %4.2e per metrecube", ni);
15 printf("\nConductivity of silicon = %3.2f mho per
    meter", sigma);
16
17
18 //Results
19 // Carrier concentration at room temperature = 3.34
    e+19 per metrecube
20 // Conductivity of silicon = 3.20 mho per meter

```

---

#### Scilab code Exa 9.12 Forbidden energy band gap

```

1 // Scilab Code Ex9.12: Page-9.32 ; (2004)
2 clc;clear;
3 e = 1.6e-19; // Electronic charge , C
4 mu_e = 0.36; // Mobility of electron; m^2V^-1s
    ^-1
5 mu_h = 0.17; // Mobility of holes , m^2V^-1s^-1
6 rho = 2.12; // Resistivity of sample, ohm metre
7 sigma = 1/rho; // Conductivity of sample, mho per
    meter
8 m = 9.1e-31; // Mass of electron , kg
9 h = 6.63e-34; // Plancks Constant, Js
10 T = 300; // Temperature, Kelvin
11 k = 1.38e-23; // Boltzman constant, joule per
    kelvin
12 // But ni = C*exp((-Eg)/(2*k*T)); // Carrier
    concentration at room temperature, therefore
13 C = 2*(2*pi*T*m*k/h^2)^(3/2); // Constant parameter
14 ni = sigma/(e*(mu_e+mu_h)); // Carrier
    concentration , per metrecube

```

```

15 b = C/ni;    // Ratio for simplicity
16 Eg = 2/e*k*T*log(b); // Band gap energy , joules
17
18 printf("\nBand gap energy = %5.4f eV", Eg);
19
20 //Result
21 // Band gap energy= 0.7927 eV

```

---

### Scilab code Exa 9.13 Hall Voltage of a semiconductor

```

1 // Scilab Code Ex9.13: Page-9.45 ; (2004)
2 clc;clear;
3 RH = 3.66e-4; // Hall coefficient , meter cube/C
4 t = 1e-03; // thickness of the specimen , m
5 Bz = 0.5; // Magnetic flux density , wb per meter
   square
6 Ix = 1e-2; // Current , A
7 VH = RH*Ix*Bz/t; // Voltage across specimen , volt
8 printf("\nVoltage across specimen = %3.2f millivolt
   ", VH/1e-3);
9
10 // Result
11 // Voltage across specimen = 1.83 millivolt

```

---

### Scilab code Exa 9.14 Hall coefficient of a semiconductor

```

1 // Scilab Code Ex9.14: Hall coefficient of a
   semiconductor : Page-9.46 ; (2004)
2 clc;clear;
3 Vy = 37e-06; // Voltage across specimen , volt
4 t = 1e-03; // thickness of the specimen , m
5 Bz = 0.5; // Magnetic flux density , wb per meter
   square

```

```

6 Ix = 20e-3; // Current , A
7 RH = Vy*t/(Ix*Bz); // Hall coefficient , meter cube
  /C
8 printf("\nHall coefficient , meter cube/C = %3.1e
  meter cube/C", RH);
9
10 // Result
11 // Hall coefficient , meter cube/C = 3.7e-06 meter
  cube/C

```

---

**Scilab code Exa 9.15** Mobility density and nature of semiconductor

```

1 // Scilab Code Ex9.15: Page-9.46 ; (2004)
2 clc;clear;
3 e = 1.6e-19; // Electronic charge , C
4 RH = -7.35e-5; // Hall coefficient , meter cube/C
5 sigma = 200; // Conductivity of the Si specimen ,
  per ohm per metre
6 n = -1/(RH*e); // Electron density , per metre cube
7 mu = sigma/(n*e); // Mobility of the charge
  carriers , square meter per voly per sec
8 printf("\nElectron density = %3.3e per metre cube",
  n);
9 printf("\nMobility = %3.3f square meter per volt per
  sec", mu);
10 printf("\nAs the RH is negative , so specimen is n-
  type");
11
12 //Result
13 // Electron density = 8.503e+22 per metre cube
14 // Mobility = 0.015 square meter per volt per sec
15 // As the RH is negative , so specimen is n-type

```

---

### Scilab code Exa 9.16 Hall Voltage

```
1 // Scilab Code Ex9.16: Page-9.47 ; (2004)
2 clc;clear;
3 e = 1.6e-19; // Electronic charge, C
4 B = 1.5; // Magnetic field, tesla
5 I = 50; // Current, ampere
6 n = 8.4e+28; // Electron density, per metre cube
7 t = 0.5e-2; // thickness of slab, metre
8 RH = 1/(n*e); // Hall coefficient
9 V_H = RH*I*B/t; // Hall voltage, volt
10 printf("\nHall Voltage = %3.3f micro volt", V_H/1e
    -6);
11
12 //Result
13 // Hall Voltage = 1.116 micro volt
```

---

### Scilab code Exa 9.17 Mobility and number of Charge carrier

```
1 // Scilab Code Ex9.17: Mobility and no of Charge
    carrier : Page-9.48 ; (2004)
2 clc;clear;
3 RH = 3.66e-4; // Hall Coefficient, metrcube/C
4 e = 1.6e-19; // Electronic charge, C
5 rho = 8.93e-3; // Resistivity of sample, ohm meter
6 n = 1/(RH*e); // Number of charge carrier, per
    metre cube
7 mu_e = RH/rho; // Mobility of electron, m^2 per
    volt per sec
8 printf("\nNumber of charge carrier = %3.3e per metre
    cube", n);
9 printf("\nMobility of electron = %4.5f squaremetre
    per volt per sec", mu_e);
10
11 //Results
```

- 12 // Number of charge carrier = 1.708e+22 per metre  
cube
- 13 // Mobility of electron = 0.04099 m<sup>2</sup> per volt per  
sec
-

# Chapter 10

## Superconductivity

Scilab code Exa 10.1 Critical field

```
1 // Scilab Code Ex10.1: Page-10.3 (2004)
2 clc;clear;
3 Tc = 3.7; // Critical temperature , K
4 Ho = 0.0306; // Critical field at zero kelvin ,
   tesla
5 T = 2; // temperature at which filed being
   calculated , K
6 Hc = Ho*[1-(T/Tc)^2]; // Critical Magnetic field ,
   tesla
7 printf("\nThe Critical field at two kelvin = %f
   tesla" , Hc);
8
9 // Result
10 // The Critical field at two kelvin = 0.021659 tesla
```

---

Scilab code Exa 10.2 Critical current and Critical field

```
1 // Scilab Code Ex10.2: Page-10.5 (2004)
```

```

2  clc;clear;
3  Tc = 7.18;    // Critical temperature , K
4  r = 1e-003; // diameter of wire , m
5  Ho = 6.5e+004; // Critical field at zero kelvin ,
    A/m
6  T = 4.2; // temperature at which field being
    calculated , K
7  Hc = Ho*[1-(T/Tc)^2];
8  ic = %pi*r*Hc; // critical current , A
9  printf("\\nThe Critical field = %e A/m" , Hc);
10 printf("\\nThe Critical current = %f A" , ic);
11
12 // Result
13 // The Critical field = 4.275855e+04 A/m
14 // The Critical current = 134.329954 A

```

---

# Chapter 11

## Lasers

Scilab code Exa 11.1 Ratio of relative population

```
1 // Scilab Code Ex11.1: Page-11.5(2004)
2 clc; clear;
3 h = 6.626e-034; // Planck's constant, Js
4 c = 3e+08; // Speed of light in free space, m/s
5 k = 8.61e-5; // Boltzmann constant, J/K
6 T = 300; // Temperature at absolute scale, K
7 lambda = 6943e-10; // Wavelength of visible light
  , m
8 E = h*c/(lambda*1.6e-19); // Energy in eV
9 rate_ratio = exp(-E/(k*T)); // Ratio of
  spontaneous emission to stimulated emission
10
11 printf("\\nThe ratio of relative population = %3.2e",
  rate_ratio);
12 printf("\\nEnergy = %3.2f eV", E);
13
14 // Results
15 // The ratio of relative population = 8.20e-31
16 // Energy = 1.79 eV
```

---



**Scilab code Exa 11.2** Energy of excited state of laser system

```
1 // Scilab Code Ex11.2: Page-11.16 (2004)
2 clc; clear;
3 a1 = 4; // diameter of laser beam for distance
         first , m
4 a2 = 6; // diameter of laser beam from second
         distance
5 d1 = 1; // First distance from laser to output beam
         spot , m
6 d2 = 2; // Second distance from laser to output
         beam spot , m
7 Div = (a2-a1)/(2*(d2-d1));
8 printf("\\nDivergence in radian = %d milliradian",
         Div);
9
10 // Result
11 // Divergence in radian = 1 milliradian
```

---

# Chapter 12

## Fibre Optics

**Scilab code Exa 12.1** Numerical aperture and acceptance angle of optical fibre

```
1 // Scilab Code Ex12.1: Page-12.6 (2004)
2 clc;clear;
3 n1 = 1.54; // Refractive index of fibre core
4 n2 = 1.50; // Refractive index of fibre cladding
5 NA = sqrt(n1^2 - n2^2); // Numerical aperture for
   optical fibre
6 // As  $\sin(\theta_a) = \sqrt{n1^2 - n2^2}$ , solving for
   theta_a
7 theta_a = asind(sqrt(n1^2 - n2^2)); //
   acceptance angle of optical fibre, degrees
8 printf("\nNumerical aperture for optical fibre = %5
   .3f", NA);
9 printf("\nThe acceptance angle of optical fibre = %4
   .1f degrees", theta_a);
10
11 // Result
12 // Numerical aperture for optical fibre = 0.349
13 // The acceptance angle of optical fibre = 20.4
   degrees
```

---

### Scilab code Exa 12.2 V and mode of optical fibre

```
1 // Scilab Code Ex12.2: Page-12.13 (2004)
2 clc;clear;
3 n1 = 1.53; // Refractive index of fibre core
4 n2 = 1.50; // Refractive index of fibre cladding
5 lamb = 1e-6; // absolute wavelength. m
6 d = 50e-6; // radius of core in m
7 V = 2*%pi/lamb*d*sqrt(n1^2 - n2^2); // volume of
   optical fibre
8 N = V^2/2; // no. of possible modes
9 printf("\nV of opical fibre = %6.2f ", V);
10 printf("\nNo. of possible modes = %5.3f ", N);
11
12 // Results
13 // V of opical fibre = 94.72
14 // No. of possible modes = 4485.735
```

---

### Scilab code Exa 12.3 Loss in signal

```
1 // Scilab Code Ex12.3: Page-12.20 (2004)
2 clc;clear;
3 po = 40; // Refractive index of fibre core
4 pi = 100; // Refractive index of fibre cladding
5 p = po/pi; // ratio of powers
6 L = -10*(log(po/pi)); // Refractive index of
   medium
7
8 printf("\nLoss in dB = %f dB", L);
9
10 // Result
11 // Loss in dB = 9.162907 dB
```

